# <u>TOSHIBA</u>

TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

# TLP181

Office Machine Programmable Controllers AC Adapter I/O Interface Board

The TOSHIBA mini flat coupler TLP181 is a small outline coupler, suitable for surface mount assembly.

TLP181 consist of a photo transistor optically coupled to a gallium arsenide infrared emitting diode. Since TLP181 is smaller than DIP package, it's suitable for high-density surface mounting applications such as programmable controllers.

- Collector-emitter voltage: 80 V (min)
- Current transfer ratio: 50% (min) Rank GB: 100% (min)
- Isolation voltage: 3750 Vrms (min)
- Operation Temperature: -55 to 110 °C
- Safety Standards
   UL recognized: UL1577, File No. E67349
   cUL recognized: CSA Component Acceptance Service No. 5A
   File No.E67349
- Option (V4) type

3

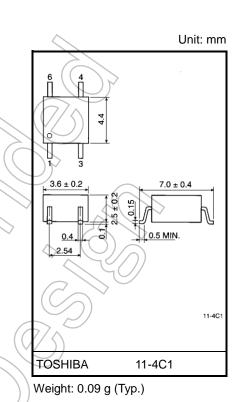
1: Anode 3: Cathode 4: Emitter 6: Collector

VDE approved : EN60747-5-5

Maximum Operating Insuration Voltage: 565 Vpk Highest Permissible Overvoltage: 6000 Vpk

Note: When a EN60747-5-5 approved type is needed, Please designate "Option(V4)"

## Pin Configuration (top view)



Start of commercial production 1993-05

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### **Current Transfer Ratio**

	Current Transfer Ratio (%) (I <sub>C</sub> /I <sub>F</sub> )			
Classification (Note 1)	IF = 5mA, VCE :	= 5V, Ta = 25°C	Marking Of Classification	
	Min	Max	$\sim$	
Blank	50	600	Blank ,Y <sup>∎</sup> ,YE,G,G <sup>∎</sup> ,GR,B,BL,GB	
Rank Y	50	150	YE, Y■	
Rank GR	100	300	GR, G, G■	
Rank BL	200	600	BL, B	
Rank GB	100	600	GB , GR , G, G■, BL , B	
Rank YH	75	150	Y• (())?	
Rank GRL	100	200	G	
Rank GRH	150	300	G•	
Rank BLL	200	400	В	$\langle$

Note 1: EX, Rank GB: TLP181 (GB)

Note: Application, type name for certification test, please use standard product type name, i, e. TLP181 (GB): TLP181

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Absolute Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit	
	Forward current	lF	50	mA	
	Forward current detating (Ta $\ge$ 89°C)	∆I <sub>F</sub> /°C	-1.4	mA/°C	
	Pulse forward current (100µs pulse, 100pps)	lfp	1	A	
Ē	Reverse voltage	V <sub>R</sub>	5	N	
_	Diode power dissipation	PD	100	mVV	)>
	Diode power dissipation derating (Ta $\ge$ 89°C)	$\Delta P_D/°C$	-2.8	mW/°C	
	Junction temperature	Tj	125	(°C)	
	Collector-emitter voltage	VCEO	80	V	
	Emitter-collector voltage	V <sub>ECO</sub>	7	) v	
ctor	Collector current	Ic	50	mA	$\bigcirc$
Detector	Collector power dissipation	Pc	150	mW	
	Collector power dissipation derating (Ta ≥ 25°C)	ΔPc/°C	-1.5	mW/°C	5 >
	Junction temperature	Тј	125	∕ <u>v</u> (	20
Stor	age temperature range	Tstg	-55 to 125	°C	GO
Ope	rating temperature range	Topr	-55 to 110	C°C	$\checkmark$
Lea	d soldering temperature (10 s)	Tsol	260	°C/	
Tota	al package power dissipation	PŢ	200	∫mW	
Tota	al package power dissipation derating (Ta $\ge$ 25°C)	ΔΡτ/°C	-2.0	mW/°C	
Isol	ation voltage (AC, 60 s, R.H. ≤ 60%) (Note 1)	BVs	3750	V <sub>rms</sub>	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Device considered a two-terminal device: Pin1, 3 shorted together and pins 4, 6 shorted together

#### **Recommended Operating Conditions**

Characteristic	Symbol	Min	Тур.	Max	Unit
Supply voltage	Vcc	_	5	48	V
Forward current	le le	_	16	20	mA
Collector current	IC	_	1	10	mA

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

**Electrical Characteristics (Ta = 25°C)** 

	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	VF	IF = 10 mA	1.0	1.15	1.3	V
LED	Reverse current	I <sub>R</sub>	V <sub>R</sub> = 5 V	_	—	10	μA
	Capacitance	CT	V = 0 V, f = 1 MHz	X	30		pF
	Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> = 0.5 mA	80	4	_	V
	Emitter-collector breakdown voltage	V <sub>(BR)ECO</sub>	I <sub>E</sub> = 0.1 mA		2_	_	V
Detector	Collector dark current	ICEO	V <sub>CE</sub> = 48 V, ( Ambient light below 1000 lx) (Note 1)	2	0.01 (2)	0.1 (10)	μΑ
Collecto		ICEO	V <sub>CE</sub> = 48 V, Ta = 85°C, ( Ambient light below 1000 lx) (Note 1)	_	2 (4)	50 (50)	μΑ
	Capacitance (collector to emitter)	CCE	V = 0 V, f = 1 MHz	_	10	$\searrow$	pF

Note 1: Please use standard electric lamp to light up the device's marking surface.

## Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition		MIn	Тур.	Max	Unit
Current transfer ratio	Ic/IF	I <sub>F</sub> = 5 mA, V <sub>CE</sub> = 5 V		50	_	600	%
		$\rightarrow$	Rank GB	100	—	600	70
Saturated CTR	IC/IF(sat) IF = 1 mA, VCE = 0.4 V Rank GE	$\sim$	_	60		%	
		$\langle \rangle$	Rank GB	30	Ι		/0
	$\bigcirc$	IC = 2.4 mA, IF = 8 mA		_	_	0.4	
Collector-emitter saturation voltage	VCE(sat)	Ic = 0.2 mA, IF = 1 mA			0.2	—	V
	9	$\square$	Rank GB			0.4	
Off-state collector current	I <sub>C(off)</sub>	VF = 0.7 V, VCE = 48 V		_	1	10	μΑ

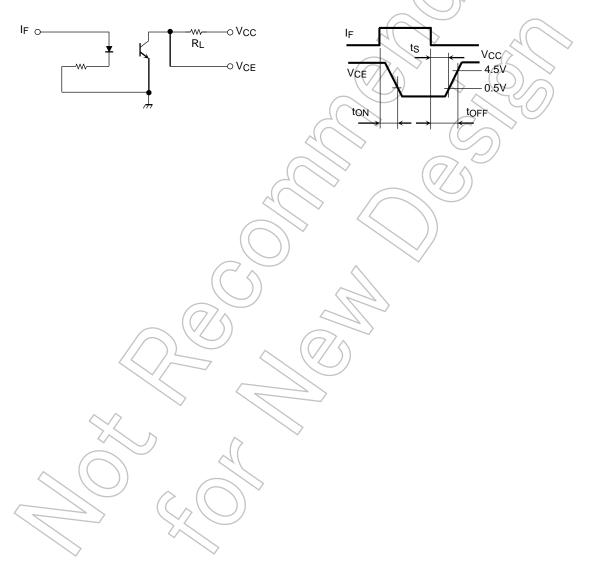
## Isolation Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance (input to output)	Cs	V <sub>S</sub> = 0 V, f = 1 MHz	_	0.8	_	pF
Isolation resistance	Rs	V <sub>S</sub> = 500 V, R.H. ≤ 60%	1×10 <sup>12</sup>	10 <sup>14</sup>	_	Ω
		AC, 60 s	3750	—	_	V
Isolation voltage	BVs	AC, 1 s, in oil	_	10000	_	V <sub>rms</sub>
~		DC, 60 s, in oil	—	10000		V <sub>dc</sub>

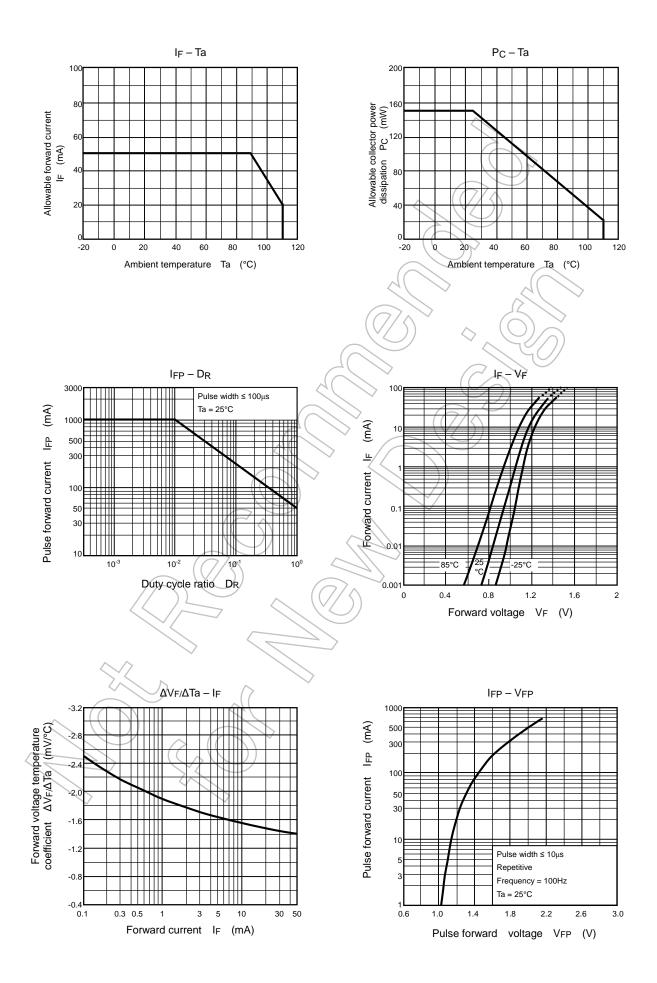
Switching Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Rise time	tr	$V_{CC} = 10 \text{ V}, \text{ I}_{C} = 2 \text{ mA}$ $R_{L} = 100\Omega$	_	2	—	
Fall time	tf		_	3	_	
Turn-on time	t <sub>on</sub>		$\nearrow$	3	_	μS
Turn-off time	toff			3	_	
Turn-on time	ton	$R_L = 1.9 k\Omega$ (Fig.1) V <sub>CC</sub> = 5 V, I <sub>F</sub> = 16 mA	F	) /2	_	
Storage time	ts		77	25	—	μs
Turn-off time	tOFF		$\mathcal{A}$	40	_	

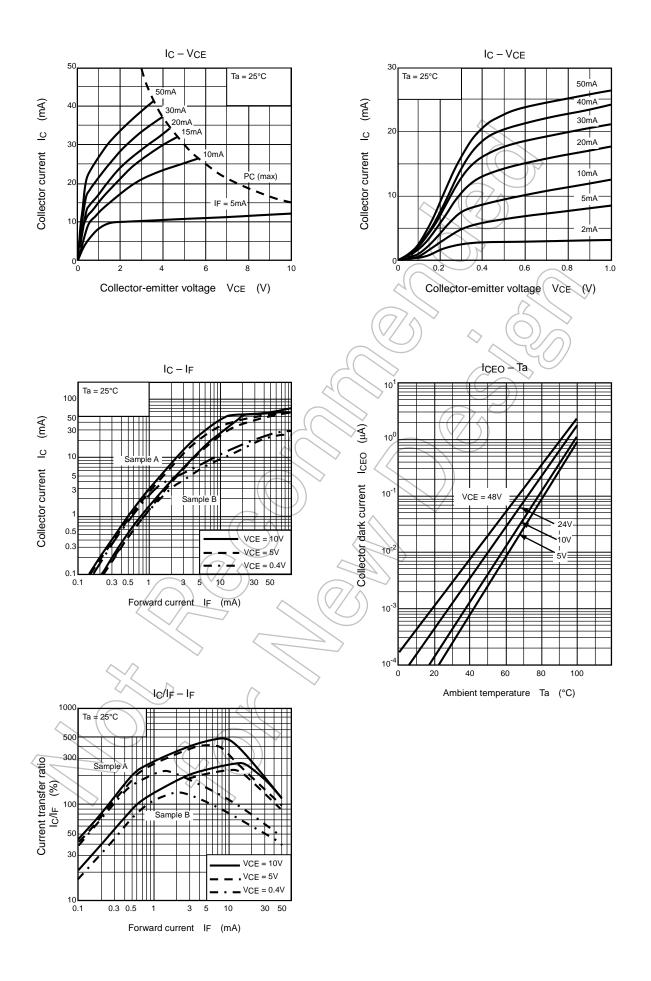
#### Fig. 1 Switching time test circuit



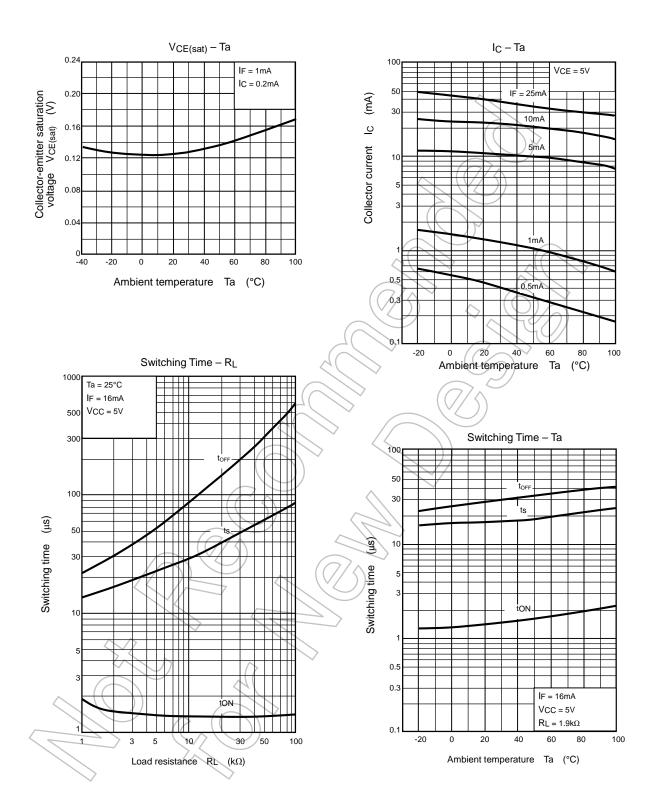
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